Electronic Supplementary Information

Arrays of CdSe Sensitized ZnO/ZnSe Nanocables for Efficient Solar Cells with High Open-Circuit Voltage

Jun Xu, Xia Yang, Qing-Dan Yang, Tai-Lun Wong, Shuit-Tong Lee, Wen-Jun Zhang and Chun-Sing Lee*

Department of Physics and Materials Science, City University of Hong Kong, Hong Kong SAR, (P. R. China); Center of Super-Diamond and Advanced Films (COSDAF), City University of Hong Kong, Hong Kong SAR, (P. R. China)

* To whom all correspondences should be addressed. E-mail: apcslee@cityu.edu.hk (C.S. Lee)

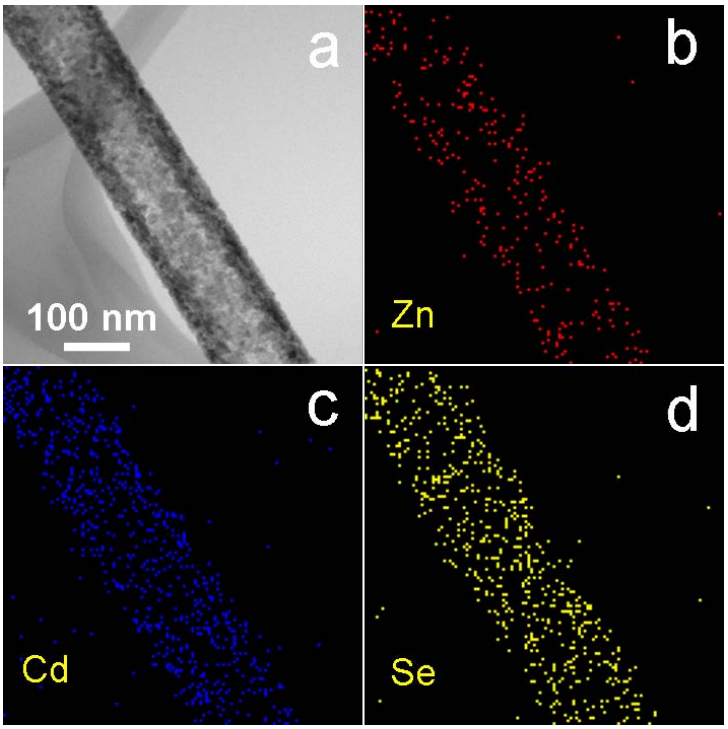

Fig. S1 (a) TEM image and (b-d) EDS mappings of a ZnSe/CdSe (55 °C) nanotube, showing homogeneous distribution of Zn, Cd, and Se throughout the tube.

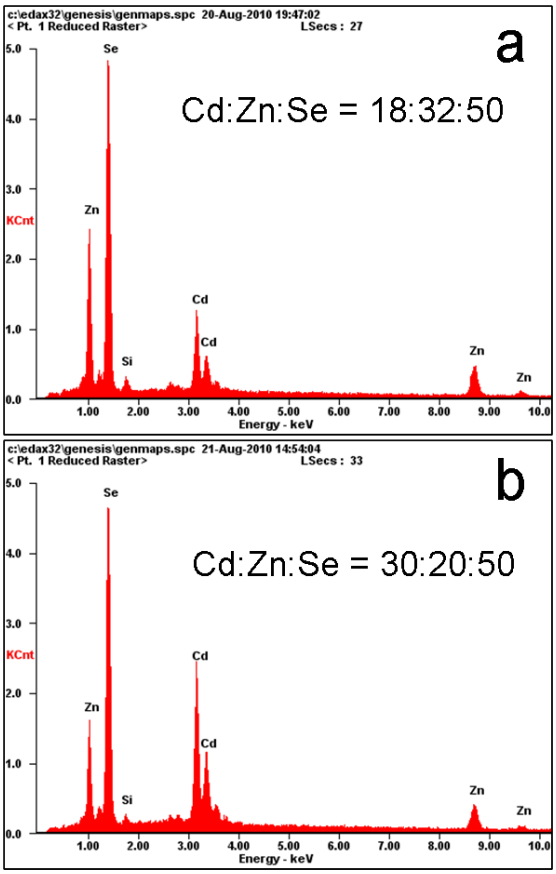

Fig. S2 EDS spectra of (a) ZnSe/CdSe (55 °C) nanotubes and (b) ZnSe/CdSe (90 °C) nanotubes prepared, respectively, by immersing the ZnO/ZnSe/CdSe (55 °C) nanocables and the ZnO/ZnSe/CdSe (90 °C) nanocables in an acetic solution to remove the inner ZnO cores.